

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

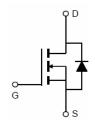
The NCEP15T11T uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- VDS =150V,ID =110A
  RDS(ON) <7.8mΩ @ VGS=10V</li>
- Excellent gate charge x RDS(on) product(FOM)
- Very low on-resistance RDS(on)
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

## **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic diagram



TO-247 top view

100% UIS TESTED!

100% AVds TESTED!

**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15T11T	NCEP15T11T	TO-247	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

<b>5</b> \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	,		
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	150	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	110	Α
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	93	А
Pulsed Drain Current	I <sub>DM</sub>	440	А
Maximum Power Dissipation	P <sub>D</sub>	300	W
Derating factor		2	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1296	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	$^{\circ}$

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	0.5	°C/W

# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	150		-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5	-	4.5	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =55A	-	6	7.8	mΩ	
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =10 $V$ , $I_{D}$ =55 $A$	70	-	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>	\/ -75\/\/ -0\/	-	10000	-	PF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =75V, $V_{GS}$ =0V, F=1.0MHz	-	2046	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	r-1.0WHZ	-	55	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	30	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =75 $V$ , $I_D$ =55 $A$	-	52	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =4.7 $\Omega$	-	69	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	21	-	nS	
Total Gate Charge	Qg	\/ -75\/  -55^	-	150		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =75V, $I_{D}$ =55A, $V_{GS}$ =10V	-	50		nC	
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -10V	-	26		nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>F</sub> = I <sub>S</sub>	-		1.2	V	
Diode Forward Current (Note 2)	Is		-	-	110	Α	
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	140		nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	498		nC	

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\!\!\mathrm{C}$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

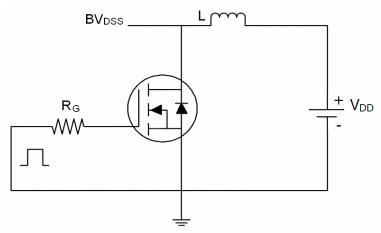
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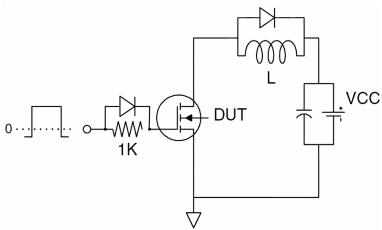


## **Test Circuit**

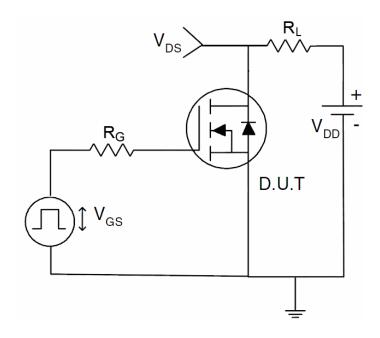
# 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit



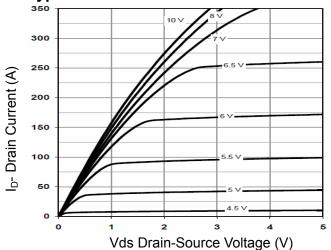
# 3) Switch Time Test Circuit



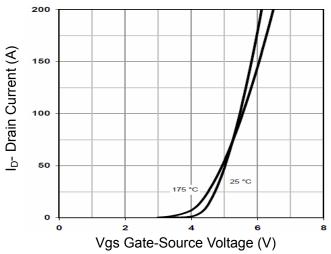
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## **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

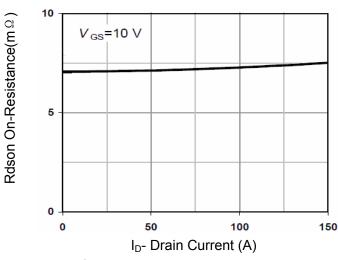


Figure 3 Rdson- Drain Current

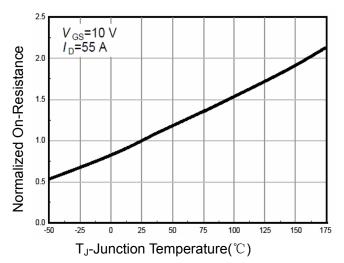


Figure 4 Rdson-JunctionTemperature

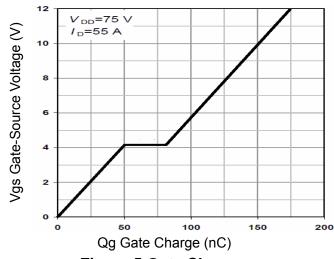


Figure 5 Gate Charge

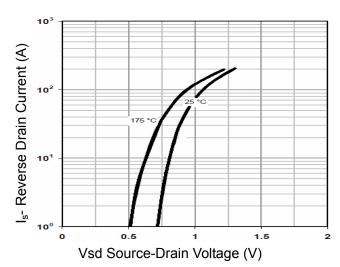
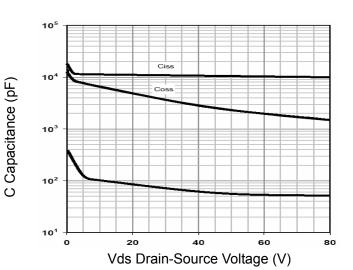


Figure 6 Source- Drain Diode Forward

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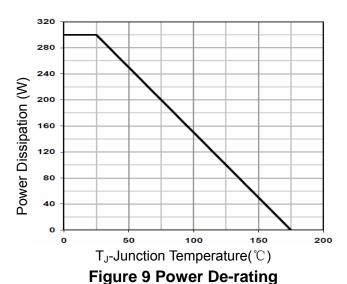
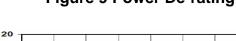
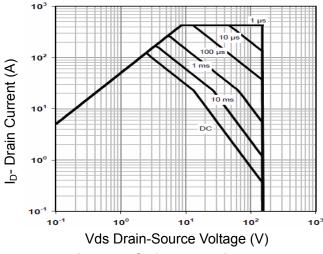
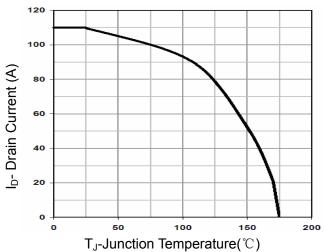


Figure 7 Capacitance vs Vds

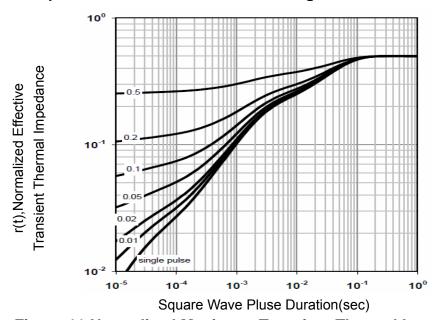






**Figure 8 Safe Operation Area** 

Figure 10 Current De-rating

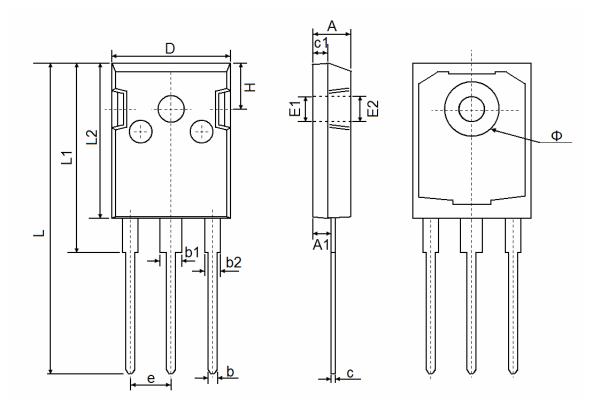


**Figure 11 Normalized Maximum Transient Thermal Impedance** 

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# **TO-247 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
Α	4.850	5.150	0.191	0.200		
A1	2.200	2.600	0.087	0.102		
b	1.000	1.400	0.039	0.055		
b1	2.800	3.200	0.110	0.126		
b2	1.800	2.200	0.071	0.087		
С	0.500	0.700	0.020	0.028		
c1	1.900	2.100	0.075	0.083		
D	15.450	15.750	0.608	0.620		
E1	3.500	REF	0.138 REF			
E2	3.600	3.600 REF		0.142 REF		
L	40.900	41.300	1.610	1.626		
L1	24.800	25.100	0.976	0.988		
L2	20.300	20.600	0.799	0.811		
Ф	7.100	7.300	0.280	0.287		
е	5.450 TYP		0.215 TYP			
Н	5.980 REF		0.235 REF			



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